**H** 573A1 Total Pages: **2** 

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# SAINTGITS COLLEGE OF ENGINEERING (AUTONOMOUS)

(AFFILIATED TO APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY, THIRUVANANTHAPURAM)

# FOURTH SEMESTER B.TECH DEGREE EXAMINATION (Regular), JULY 2022

# (2020 SCHEME)

Course Code: 20ECT292

Course Name: Nano Electronics

Max. Marks: 100 Duration: 3 Hours

#### PART A

# (Answer all questions. Each question carries 3 marks)

- 1. Define de-Broglie wavelength and screening length in mesoscopic systems.
- 2. Define density of states (DoS) in a nano structures. Write the DoS expression for 2D, 1D, and 0D nanostructures.
- 3. Describe the basic concept of Physical Vapour Deposition for nanomaterial.
- 4. List the advantages of Molecular Beam Epitaxy.
- 5. Describe the working principle of Atomic Force Microscope.
- 6. Point out the reason for using X-Ray diffraction analysis for nanoparticles.
- 7. Illustrate the concept of modulation doping.
- 8. Explain hot electron.
- 9. Describe the working principle of quantum dot laser.
- 10. List any five applications of MODFET.

#### PART B

(Answer one full question from each module, each question carries 14 marks)

#### **MODULE I**

11. Starting from Schrodinger equation, show that the density of states in a 1D (14) semiconductor material is directly proportional to  $\frac{1}{\sqrt{E}}$ .

#### OR

12. Explain quantum wells, wires and dots with figure and compare each.

(14)

# **MODULE II**

13. Illustrate thermal oxidation process. Differentiate dry and wet oxidation methods.

. (14)

### OR

14. Explain DC sputtering method for nanomaterial deposition. Sputtering technique cannot be used for fabricating non conducting layers. Justify the statement.

### **MODULE III**

15. Illustrate different types of specimen interactions taking place in a sample during (14) Scanning Tunnelling Microscope.

OR

16. Compare Scanning Tunnelling Microscope and Atomic Force Microscope with (14) suitable diagram.

# **MODULE IV**

17. Illustrate the working principle of operation of Resonant tunnelling diode (14)

OR

18. Explain the Aharonov-Bohm effect to induced phase variations in electron waves with the application of magnetic field with the help of diagrams and equations. (14)

# **MODULE V**

19. Analyze the structure of Single Electron Transistor (SET) with neat diagram. (14)

OR

20. Explain the working principle of Carbon Nano Tube (CNT) transistors and list the (14) types.

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